We claim:

1. A process for producing a microroughness on a surface, the process which comprises:

forming, in a single process step, semiconductor grains directly from a process gas such that the semiconductor grains are distributed on a surface for producing a microroughness on the surface.

2. The process according to claim 1, which comprises:

providing the semiconductor grains as grains selected from the group consisting of Si grains and Ge grains; and

providing the process gas as a gas selected from the group consisting of SiH_4 or GeH_4 .

- 3. The process according to claim 1, wherein the step of forming the semiconductor grains is performed in a temperature range extending from 500 degrees Celsius to 600 degrees Celsius.
- 4. The process according to claim 1, wherein the step of forming the semiconductor grains is performed at a pressure between 13 Pascal and 80 Pascal.

- 5. The process according to claim 1, wherein the step of forming the semiconductor grains is performed in a period lasting between 5 minutes and 60 minutes.
- 6. The process according to claim 1, which comprises using a material selected from the group consisting of an oxide, a nitride and a Si-substrate for providing the surface.
- 7. The process according to claim 6, which comprises precleaning the Si substrate.
- 8. The process according to claim 7, wherein the precleaning step includes at least one cleaning step selected from the group consisting of a piranha cleaning, an RCA cleaning and a HF-dip cleaning.
- 9. The process according to claim 1, which comprises providing the process gas with an H_2 dilution in a range from 1:20 to 1:0.2.
- 10. The process according to claim 1, which comprises providing the process gas with an N_2 dilution in a range from 1:100 to 1:5.
- 11. A process for producing a microroughness on a surface, the process which consists of:

forming semiconductor grains distributed on a surface for producing a microroughness on the surface by forming the semiconductor grains directly from a process gas.